## Lone-pair-induced formation of intrinsic one-dimensional SbSX (X = Cl, Br, I) helix chain materials

## Supporting Information

Ziye Zhu,<sup>1,2</sup> Shu Zhao,<sup>1,2</sup> Xiaoping Yao,<sup>1,2</sup> and Cong Hu<sup>1,\*</sup>

<sup>1</sup>School of Engineering, Westlake University, Hangzhou 310030, China <sup>2</sup>School of Materials Science and Engineering, Zhejiang University, Hangzhou 310027, China

 $<sup>^{\</sup>ast}$ hucong@westlake.edu.cn



Figure S1. Electronic band structure of 1D SbSX (X = Cl, Br, I) helix-chains calculated with PBE functional.



Figure S2. (a) Phonon spectra of SbSCl helix chain type I phase. (b) Atomic displacement patterns corresponding to the torsional mode (the red line in (a)). (c) Phonon spectra of SbSCl helix chain type II phase. The three non-red colorful lines indicate the three acoustic modes, and the red-line optical mode indicates the torsional mode.



Figure S3. The evolution of energy of 1D SbSCl helix-chain type I phase (**a**) and type II phase (**b**) simulated with ab initio molecular dynamics at 300 K. The inset illustrates the final structures at 4 ps.



Figure S4.  $(\mathbf{a})(\mathbf{b})$  The average bond length and radius of 1D SbSBr and SbSI helix-chain type II phase as the function of elongation strains.  $(\mathbf{c})(\mathbf{d})$  Variation of average change of bond angle of Sb-S-Sb and S-Sb-S in 1D SbSBr and SbSI helix-chain type II phase under different elongation strains, compared to the equilibrium state.